Seat No.		Set P
М.\$	Sc. P	ysics (Material Science) (Semester - I) (New) (NEP CBCS) Examination: March/April - 2025 Mathematical Physics (2321101)
•		nursday, 15-May-2025 Max. Marks: 60 M To 05:30 PM
Instruct	ions:	1) All questions are compulsory. 2) Figures to the right indicate full marks.
Q.1 A)	2)	Which of the following is NOT an algebraic operation in complex numbers? a) Addition b) Exponential c) Multiplication d) Division Cauchy's Integral Theorem states that: a) The integral of a function along a closed contour is zero b) The integral of a function along a contour depends on the contour itself d) The integral of a function along a contour is infinity The Fourier transform of a Gaussian distribution in the time domain results in a: a) Gaussian distribution in the frequency domain c) Sine function in the frequency domain d) Delta function in the frequency domain
	4)	In the Fourier series representation of a square wave, the coefficients corresponding to odd harmonics are: a) Zero b) Non-zero c) Constant d) Negative
	5)	The number of arbitrary constants in the general solution of differential equation of second order is a) 1
	6)	The non-zero Particular Integral can be found out for differential equation. a) Homogeneous b) Non-Homogeneous c) Second order Homogeneous d) None of these

		7)		Hilbert spa Anticomm Additivity	ce, which pi nutativity	roperty (does b) d)	Distrik	ner product outivity ciativity	satisfy?	
		8)	a)	0	ne zero matı	rix?	b)	1	·	finad	
			C)	-1			d)	rne ra	ank is unde	iinea	
	B)	wr a) b) c) d)	A set the The hoo Ca point The	e set can be le Wronskia mogeneou auchy's Inte lint in terms	ions is a core expressed an of a set o sequation vegral Formule of its conto	d as a ling of solution with constances ala expresour integ	near ons to stant sses ral.	combin a sec coeffice the va	nation of the ond-order cients is alw llue of a fun	others. vays zero. ction at a	04
Q.2	Ans	wei	' the	e followinç	g question ((Any Si	x)				12
	a)	Sh	ow	that given	matrix is uni	itary ma	trix A	$\mathbf{I} = \begin{bmatrix} i \\ 0 \end{bmatrix}$	$\begin{bmatrix} 0 \\ 1 \end{bmatrix}$		
	b) c) d)	Find the Norms of given equation $f(t) = t + 2$ Define De-Moivre's theorem by exponential function.									
	e)			Z							
	C)			$4\frac{d^2y}{dx^2} + 4\frac{dy}{dx}$	y + y = 0						
	f) Find $L(te^{2t})$ g) Define in a_0 , a_n and b_n in Fourier series.										
	h)	Fir	ıd, t	he Residue	$e ext{ of } f(z) = \frac{1}{2}$	$\frac{z^2}{Z^2 + a^2}$					
Q.3	Ans				g question (12
	a)	Co	nsid	der the fund	ction $f(z) =$	$\oint \frac{e^z}{Z^2 - 2Z}$	$\frac{1}{1+2}$ dz	7			
	b)	i) ii) De	C		ne singular _l e residues a Diagram.	-	-		lar points		
	,	De	tern	mine linear	independer , −2, 1), (1, 1		llowi	ng Set			
	d)				$\frac{dy}{dx} + 29y =$						
Q.4	Ans				g question (-				12
	a)	So	lve	the differer	ntial equatio	$n \frac{dy}{dx} + y$	cotx	$= \cos x$	x		
	b)			ate the inte	gral $f(z) =$ rclockwise.	$ \oint \frac{\sin(z)}{Z^2 + 4} \ dz $	dz w	here, C	is the circle	e Z = 3	

c) Determine whether the following in R³ is linearly independent.

$$\{(1,-2,1),(2,1,1),(7,-4,1)\}$$

Q.5 Answer the following (Any Two)

12

- a) Find $L(te^{-2t} \sin 2t \sin 3t)$
- **b)** Solve $\frac{d^2y}{dx^2} 10\frac{dy}{dx} + 25y + 0$
- Find the inverse of a matrix $A = \begin{bmatrix} 7 & 2 & 1 \\ 0 & 3 & -1 \\ -3 & 4 & -2 \end{bmatrix}$

Seat No. Set	Р
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M.Sc. Physics (Material Science) (Semester - I) (New) (NEP CBCS)

			Examinatio Solid State		-	
•			turday, 17-May-2025 To 05:30 PM		Max. Mark	:s: 60
Insti	ructio	,) All questions are cor) Figures to the right i	•	marks.	
Q.1	-	I) The a)	ose correct alternation e Bloch theorem is cropertie Superconductivity	ucial for und s b)	Band structure in solids	08
	2	a) b) c)	e Meissner effect den) Perfect diamagneti) Magnetic susceptib) Curie-Weiss behav) None of the above	sm in super oility in ferrit	es	
	3	a)	e Neel temperature is) Superconductivity) Ferrimagnetism	b)	with Antiferromagnetism Ferroelectricity	
	4	clo a)	nich type of polarization oud?) Ionic) Electronic	on is due to b) d)	the distortion of the electron Orientational Dielectric	
	Ę	a) b)	e Kronig-Penney mod) The energy gap in) Susceptibility in mad) Polarization mechad) None of the above	semiconduo Ignetic mate	etors	
	6	a)	perconductivity is des Low temperatures Room temperature	b)	High magnetic fields	
	7	a)	rrimagnetic materials) Equal and opposite s	spins b)	Unequal opposing spins	

		 a) Magnetic permeability and susceptibility b) Polarizability and dielectric constant c) Electrical conductivity and temperature d) None of the above 				
	B)	 Fill in the blanks: a) The energy bands in solids arise due to the potential. b) Superconductors exhibit perfect diamagnetism due to the effect. c) Antiferromagnetic materials have a critical temperature called the d) The equation is used to calculate the internal field in a dielectric. 	04			
Q.2	a) b) c) d) e) f)	Discuss the significance of the Meissner effect in superconductors. What is the Curie point? Explain the electronic polarization in dielectrics. Write about the energy gap in semiconductors.				
Q.3	a) b)	Describe the electrical conductivity in metals. Write about the Langevin theory of paramagnetism.	12			
Q.4	a)	wer the following (Any Two). Derive the Clausius-Mossotti equation. Explain the dipole theory of ferroelectricity. Write a note on saturation magnetization and its temperature dependence.	12			
Q.5	Ans a) b) c)	wer the following (Any Two). Describe the Josephson effect and its applications. Discuss the thermodynamics of superconductors. Write a detailed note on ferrimagnetic materials.	12			

The Clausius-Mossotti equation relates

8)

Seat No.					Set	P			
M.Sc. Physics (Material Science) (Semester - I) (New) (NEP CBCS) Examination: March/April - 2025 Analog and Digital Electronics (2321106)									
•		Monday, 19-I AM To 05:30	•		Max. Marks	: 60			
Instructi	ons:		ons are compulsory o the right indicate		arks.				
Q.1 A)		If a signal p			inhibited by sending a LOW ut is HIGH, the gate is a(n): NAND OR	80			
	2)	a) It has anb) It has inc) It contain	e following is true an internal memory terfacing circuits ns ALU, CU, and retarvard architecture	egiste	·				
	3)		ll serial load and int		ept a parallel input, or a shift features, called? end around conversion				
	4)	The output HIGH when a) A = 1, B = c) A=1, B=	=1, C=0	b)	ee inputs. A, B, and C, is A=0, B=0, C=0 A=1, B=0, C=1				
	5)	a) infinite of	erational amplifier houtput impedance pandwidth		zero input impedance				
	6)	A series dis a) linear re c) shunt re	gulator	b)	example of a switching regulator dc-to-dc converter				
	7)	a) all input	of a NOR gate is H s are HIGH ut is LOW		any input is HIGH				

		in a)	hich of the following logical o Boolean algebra? inversion OR	perati b) d)	ions is represented by the + sig AND Complementation	n
	В)	1) Th 2) Or 3) A lea 4) Pr	p-amp circuits are used in microprocessor with the nece ast two memory ICs: ROM or	buffe v essary EPR	er is with the input voltag oltmeters. / support circuits will include at OM, and a RAM. True/ False t have slight modifications to ru	
Q.2	Ansv a) b) c) d) e) f) g) h)	Define What What Define What Define What What	e following. (Any Six) the term common mode rejective the operations performed is instrumentation amplifier. The slew rate. The slew rate is Input bias current. The voltage regulator. The opcode fetch cycle. The differential gain related to a	I by A	LU of 8085.	12
Q.3	Ansv a) b) c) d)	Draw List th Descr	e following. (Any Three) the circuit diagram of an Op- ne Software and Hardware intellibe some of the characteristic the logic diagram of SR flip-f	errup	oractical Op-amp?	12
Q.4	Ansva) b)	What regula Draw config Write	e following. (Any Two) is switching regulator? What ator? Explain them in details we the circuit of summing amplifuration. an equation for the output vo in briefly about bus structure	with s ier us Itage	uitable figure? ing inverting amplifier for this circuit	12
Q.5	Ansv a) b) c)	What at the Draw	e following. (Any Two) is comparator? How it can be output from a Sine-wave? and explain the architecture of in the difference between cor	of 808	35 microprocessor.	12

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No.	Set	

M.Sc. Physics (Material Science) (Semester - I) (New) (NEP CBCS) Examination: March/April - 2025 Research Methodology in Physics (2321105)

		ľ	research Methodology i		ysics (232 i 103)	
			day, 24-May-2025 o 05:30 PM			Max. Marks: 60
Instructio	ons	-	all questions are compulsory		arks.	
Q.1 A)		oose The a) b) c) d)	08 ation			
	2)	a)	V is spectroscopy cannot a don't interact merge	b)	e compounds that interact none of the abov	_
	3)	is _ a)	selecting laser operating con possible not defined	b)	ns, control over mi impossible both a) and b)	crostructure
	4)	a)	C sputtering, bias is Negative No	b)	ed to the target ma Positive All of the above	aterial.
	5)	poin a)	istive thermal deposition ca ts. boiling melting	b)	osit materials with decimal none of the abov	
	6)	a)	TEM provides imagest medium resolution low resolution		poor resolution high resolution	
	7)	tech a)	litative methods are probab iniques, the method of Qual Questionnaire Depth Interview	litative	research is Attitude Scales	
	8)	a)	ctronic interview can be con Telephonic Personal	b)	d by Fax All of the above	

	D)	In PLD, kinetic energies of ablated particles are high enough to promote surface diffusion. (True/False) In thermal evaporation, films in the thickness range of angstroms to microns are obtained. (True/False) 3) sampling is a probability sampling method. In sputtering, magnets behind cathode trap electrons.	04
Q.2	Ans a) b) c) d) e) f) g)	What are the applications of UV-Vis Spectroscopy? State the physical conditions of DC and RF sputtering. Define Quantitative research method. State the various tools for data analysis. Draw the neat labeled diagram of electrodeposition method. What are the applications of FTIR Spectroscopy. Enlist the Data Processing strategies. Write the applications of Pulsed Laser Deposition.	12
Q.3	Ans a) b) c) d)	wer the following. (Any Three) Write a note on Patents. Draw the neat labeled diagram of HRTEM instrument. Define physical and chemical vapour deposition. Write a note on Applied Vs. Fundamental research methods.	12
Q.4	a)	Explain different techniques and methods of good sampling. Write in detail about the concept of Chemical Bath Deposition. Write in detail about the construction and working of SEM.	12
Q.5	Ans a) b) c)	Write a note on Review of Literature. What is Research Methodology? What are the requisites for Good Scientific Research? Explain the construction and working of Fourier Transform Infrared Spectroscopy.	12

Seat No.		Set P							
M	M.Sc. Physics (Material Science) (Semester - II) (New) (NEP CBCS) Examination: March/April - 2025 Quantum Mechanics (2321201)								
-	Day & Date: Wednesday, 14-May-2025 Max. Marks: 60 Time: 11:00 AM To 01:30 PM								
Instru	ctions	 All questions are compulsory. Figures to right indicate full marks. 							
Q.1 A	,	Pose correct alternative. Raising operator is defined as a) $L_x + iL_y$ b) $L_x - iL_y$ c) $iL_z - iL_y$ d) $iL_x - iL_z$							
	2)	Momentum of particle by de-Broglie relation is to its wavelength. a) inversely proportional b) directly proportional c) in phase d) out of phase							
	3)	Potential energy of a particle in harmonic oscillator having mass m is a) $m\omega^2x^2$ b) $(1/2)m\omega^2x^2$ c) $mr\omega^2$ d) $(1/2)mv^2$							
	4)	If Ψ_a and Ψ_b are said to be orthogonal to each other, then which of the following is true. a) $\langle \Psi_a \Psi_b \rangle = 1$ b) $\langle \Psi_a \Psi_b \rangle = \infty$ c) $\langle \Psi_a \Psi_b \rangle = \sqrt{1/2}$ d) $\langle \Psi_a \Psi_b \rangle = 0$							
	5)	The commutation relation between $[x, P_x]$ and $[\partial/\partial x, x]$ is a) $i\hbar, 0$ b) $0, i\hbar$ c) $-i\hbar, 1$ d) $i\hbar, 1$							
	6)	The eigen value of L^2 is a) $l(l+1)\hbar^2$ b) $l(l-1)\hbar$ c) $l(l^2+1)\hbar^2$ d) $l(l+1)\hbar$							
	7)	The minimum energy of particle confined to one dimensional rigid box is by substituting n equal to a) one b) zero c) half d) two							
	8)	The eigen value of spin matrices are a) ± 2 b) 0 c) ± 1 d) ∞							

	B)	 Fill in the blanks OR write true/false. 1) Inner product of bra and ket in Quantum Mechanics is always 1. (True/False) 2) Probability density is always positive. (True/False) 3) For a free particle the potential energy V(x) = 4) The linear momentum operator is given by 	04
Q.2	a) b) c) d) e) f)	Define Hamiltonian operator. Write about the energy of harmonic oscillator. What is the probability density? Define the orthogonality and normalization. Write in short about the Dirac delta function. What is Compton effect? What is meant by rigid box? What is a complex function? Give an example.	12
Q.3	a) b) c)	Swer the following. (Any three). State and prove Ehrenfest theorem Part II. Prove that group velocity (V_g) is equal to velocity of material of particle (V_g) Define the different postulate of Quantum mechanics. Explain unitary transformation.	12 ′).
Q.4	Ansa) b) c)	What is Schrodinger wave equation? Write in detail about Schrodinger time independent wave equation.	12
Q.5	Ans a) b) c)	Obtain eigen values of operators L^2 and Lz . Describe the Pauli spin matrices. Explain i) Schartz's Inequality ii) State vector iii) Span iv) Basis	12

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M.Sc. Physics (Material Science) (Semester - II) (New) (NEP CBCS)

			Examination: Ma Electrodynami		•
•			Friday, 16-May-2025 AM To 01:30 PM		Max. Marks: 60
Insti	ructio	ons:	 All questions are compulso Figures to the right indicate 	-	narks.
Q.1	A)	C h	oose correct alternative. The electrostatic energy in ar of the following?	ı elect	08 ric field does not depend on which
			a) Magnitude of chargesc) Applied electric field	b) d)	Permittivity Flux lines
		2)	If the electric potential is give calculated? a) Electrostatic energy	b)	Electric field intensity
			c) Electric flux density	d)	Permittivity
		3)	Electric field intensity is a a) Scalar c) Both (a) and (b)	b)	quantity. Vector None of the above
		4)	The skin effect is a phenomera) Insulators c) Conductors		Dielectrics
		5)	Lorentz electric force has dire a) Similar to electric field c) Scalar quantity	_	
		6)	Electric intensity at any point point. a) Electric flux c) Potential gradient	in an (b) d)	•
		7)	The Biot-Savart's law is a ger a) Kirchhoff's law c) Ampere's law		Lenz's law
		8)	The skin depth is used to find a) DC resistance c) Permittivity	b)	n parameter? AC resistance Potential

	B)	 Write True/False. The work done in moving a test charge from one point to another in an equipotential surface is zero. When curl of a path is zero, the field is said to be conservative. In static magnetic field only magnetic dipole exist. The magnetic field intensity will be zero inside a conductor. 	04
Q.2	Ans a) b) c) d) e) f) g) h)	wer the following. (Any Six) State Biot-Savart law. Explain the electromagnetic force. How electromagnetism works? Define Poynting vector. What is an electric field? Write Maxwell equation derived from Faradays law. What is an electromagnetic wave? Define Skin effect.	12
Q.3	Ans a) b) c) d)	wer the following. (Any Three) Explain differential form of Ampere's law. Explain energy stored in electric field. State the boundary condition for an electrostatic field Ē. Explain Maxwell displacement current.	12
Q.4	Ans a) b) c)	wer the following. (Any Two) What is gauss law? Explain differential form of its. Discuss electromagnetic plane waves in stationary medium. Explain the concept of Thomson cross section.	12
Q.5	Ans a) b) c)	wer the following. (Any Two) Explain boundary condition between conductor and free space. State and prove Poynting theorem. Explain in short radiation from a half wave antenna.	12

Seat No.					Set	P
N	É	terial Science) (Se xamination: Marc Classical Mechanic	h/Ap	oril - 2025	EP CBCS)	
,	Date: Tuesday, 20- 11:00 AM To 01:30	•			Max. Marks	: 60
Instru	-	ions are compulsory to the right indicate fo		arks.		
Q.1	a) Holono c) Scleror	the constraints are in mic comous	b) d)	Non-holonomic Rheonomous		80
	a) Positionb) Momenc) Both Podd) Cyclic of		m co	oordinates		
	3) Which is t mechanic a) F=m/a c) F=m+a		atem b) d)	ent of 2 nd law of Ne F=ma F=m-a	ewtonian	
	4) fo a) ∈> 1 c) ∈= 1		b)	of eccentricity. $\in < 1$ $\in = 0$		
	a) Invariar		b)	under Galilean trans Variant changes its sign	sformation.	
	6) Degrees of a) 0 c) 3		eel _ b) d)	1		
	7) Which of t a) [X,Y]= [c) [X, Y]=		b)	oisson bracket? [X,Y]=2[Y,X] [X,X]=[Y,Y]=1		
	8) The gene a) Identity c) Zero	rating function F1(q,0		generates Exchange Infinite	transformati	on.

	B)	 Fill in the blank OR true /False. The motion of the planets around the sun is the example of the motion under central force field. (True/False) In Lagrange's equation, the motion of the system has been described by force. (True/False) The equation of Jacobi's Identity is As per Kepler's third law of planetary motion, square of a time period is directly proportional to cube of a 	04
Q.2		wer the following. (Any Six)	12
	-	Define central force and give its characteristics? How to analyse the orbits?	
	c)	What is the Jacobi integral?	
	-	Define the conservation of linear and angular momenta.	
	-	Write in short about the open system. What is Euler-Lagrangian differential equation?	
		Write the condition for transformation to be canonical.	
		What is the constant of motion?	
\cap 2	۸nc	war the following (Any Three)	12
Q.3		wer the following. (Any Three) Give an account about conservation of energy in case of mechanics	12
	,	of particles.	
	b)	What are constraints? Explain in detail about their types with suitable	
	c)	examples. Check whether the transformation defined as Q=1/p, P=qp ² is	
	c,	canonical or not.	
	d)	State Hamilton's variational principle and derive the Lagrange's	
		equation of motion form it?	
Q.4	Ans	wer the following. (Any Two)	12
	a)	Explain	
		Gauge invariance of Lagrangian equation	
	b)	 Gyroscopic forces Explain and prove the principle of least action. 	
	c)	Derive an equivalent equation for reduction to one body problem from	
	,	two body problem.	
Q.5	Λne	wer the following. (Any Two)	12
Q. J	a)	Elaborate the differences between Classical Mechanics and	12
	,	Quantum Mechanics.	
	b)	Apply the Hamilton's equations to derive the equations of motion for	
	c)	simple pendulum and linear harmonic oscillator. Write short note on	
	U)	1) Artificial Satellite	
		2) Rutherford scattering	

Seat No.			Set P						
M.Sc. Physics (Material Science) (Semester - III) (New) (NEP CBCS) Examination: March/April - 2025 Statistical Physics (2321301)									
-			Thursday, 15-May-2025 Max. Marks: 60 NM To 01:30 PM						
Instr	uctio	ns:	 All questions are compulsory. Figure to the right indicate full marks. 						
Q.1	A)		First and second law of thermodynamics are related by the relation a) dU=TdS-VdP b) dU=TdS+PdV c) dU=PdV-TdS d) dU=TdS-PdV						
		2)	Helmholtz function is the amount of useful work done by a thermodynamic system at constant a) pressure b) temperature and volume c) temperature and pressure d) pressure and volume						
		3)	"At absolute zero the entropy of pure crystal is zero" is the statement of which law of thermodynamics? a) First law b) Second law c) Third law d) Fourth law						
		4)	In a grand canonical ensemble, a system A of fixed volume is in contact with a large reservoir B. Then a) A can exchange neither energy nor particles with B b) A can exchange only energy with B c) A can exchange both energy and particles with B d) A can exchange only particles with B						
		5)	In which process the pressure of the system remains constant? a) isothermal process b) isobaric process c) isometric process d) isochoric process						
		6)	In Maxwell relations, $(\partial T/\partial V)s = ?$ a) $-(\partial V/\partial S)_T$ b) $-(\partial P/\partial S)_V$ c) $(\partial S/\partial P)_T$ d) $(\partial S/\partial V)_T$						
		7)	What does occur at a critical point in critical phenomenon? a) phase transition b) symmetry breaking						

d)

scaling laws

c) universality

		8)	Ele	ectron is an example of wl	hich :	statistics?				
			a)	Bose Einstein statistics	b)	Maxwell Boltzmann statistics				
			c)	Fermi Dirac statistics	d)	None				
	B)	Fil	l in	the blanks OR write true	e/fals	se:	04			
		1) 2)	Du			canonical pair. (True/False) perature of a substance remains				
		3) 4)		ne average K.E. of a harme BE statistics particles hav						
Q.2	Ans			e following question (An	-	-	12			
	a)	Whi tran			cons	stant during the process of phase				
	b)			one example of first order p	ohas	e transition.				
	-			the statistics obeyed by pl		and electron.				
	•			s thermodynamic potential						
	•			about statistical ensemble. s phase space?						
	-			s the entropy of system?						
Q.3	Ans	swer	the	e following (Any Three).			12			
	•			note on chemical potentia						
	b)			s about the thermodynam	-					
	d)			about the condition for pha a note on probability calcul		•				
	u	V V I I	ic a	Thole on probability calcul	atioi					
Q.4	Answer the following (Any Two).									
	a)	Wr	ite a	a note of Black body radia	tion	and Planck distribution.				
	p)			and discuss the diagram of						
	c)	De	tine	and explain the laws of the	nerm	odynamics with examples.				
Q.5	Ans	swer	the	e following (Any Two).			12			
	a)			and discuss the Ehrenfest	-					
	p)			in detail about the Maxwe						
	c)	ĽΧ	plai	in about the statistical ens	embl	es and their types.				

Seat No.	Set	Р
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M.Sc. Physics (Material Science) (Semester - III) (New) (NEP CBCS)

•	VII.O	0. 1	iiy Si	Examinati	ion: Marc	ch/	April - 2025 sics (2321302)	OBOO,
-				ırday, 17-Мау-202 Го 01:30 РМ	5		Ма	x. Marks: 60
Insti	ructi	ions		All questions are c Figures to the righ			marks.	
Q.1	A)		The a)	se correct alterna singlet system of Para-helium Ortho-helium		b)	o is called a positively helium ion a negatively helium ior	08
		2)	scat a)	ch of the following ttering? Total Energy Kinetic Energy			nserved during Raman Momentum Electronic Energy	
		3)	give a)		on from va		us s levels to lowest p le principle series fundamental series	vel
		4)	a)	ase of LS coupling 1,2,3,4 2,3,4	I ₁ = 1 , I ₂ =	b)	then J = 0,1,2,3 0,1,2,3,4	
		5)	adja	n increasing quant acent levels in aton decreases remain constant	ns		nergy difference betwee increases zero	en
		6)	Ator a) c)	mic spectra is an e line spectra band spectra	example o	f b) d)	continuous spectra both a and b	
		7)	a) b) c)	Spin quantum nu	mber m number ım numbe	er	epends on their	

	8)	Syr	mm	netric top moi	iecuies nave _	·		
		a	a)	IA=IB=IC		b)	IA=IB≠IC	
		C	c)	IA≠IB=IC		d)	IA=O, IB≠IC	
	В)	 1) 2) 3) 	Sp ca If (Ex Sp Th	lled Stark efformation of nution of the contraction	ect. (True/Fals clear reaction rue/False) omentum dep	se) is po ends	m in presence electric field is esitive the reaction is on s. (True/False) ed in far IR region.	04
Q.2	a) b) c) d) e) f)	What Define What Define	nt ane e ane ne istinction in the interest in th	interaction entroduction entroduction into the covalent interest meant by dissociation	um states of a nergy of an at chen back eff raction. atomic molec	om. ect. ule?	ctron in an atom? tom.	12
Q.3	a) b) c)	Write Disc State	e ir us: e a	s about origir Ind explain P	Any Three) o valence elect of spectral life auli's Exclusion vibrating diate	ne. on Pri	nciple.	12
Q.4	a) b)	Write Disc	e ir		t the jj couplin (-ray and Aug	_	nsition.	12
Q.5		Wha Expl	at is ain	n in detail abo	ructure? Elab out anharmoni	c osc		12

Seat No.		Se	t P				
M.Sc. Physics (Material Science) (Semester - III) (New) (NEP CBCS) Examination: March/April - 2025 Physics of Nanomaterials (2321307)							
•		nday, 19-May-2025 Max. Ma To 01:30 PM	rks: 60				
Instruc) All questions are compulsory.) Figures to the right indicate full marks.					
Q.1 A	-	Which of the following is a bottom-up technique for nanostructure fabrication? a) Sputtering b) Ball milling c) Polyol route d) Photolithography	08				
	2)	The primary effect of quantum confinement in semiconductor nanostructures is: a) Reduced bandgap b) Increased optical absorption c) Reduced electron mobility d) Decreased surface energy					
	3)	Raman Spectroscopy is primarily used for: a) Measuring electrical conductivity b) Identifying chemical bonds and vibrational modes c) Measuring the absorption spectra d) Determining the density of states					
	4)	Which of the following processes can be used for thin film deposition?					

a) Poling

c) Metals

b) Rapid solidification

a) Semiconductors

c) Molecular beam epitaxyd) Colloidal precipitation

5) Hopping conduction is most likely to occur in:

b)

ď)

Insulators

Thin films

		The phenomenon of electroluminescence is best observed in:	
		 a) Organic light-emitting diodes b) Fluorescent materials c) Metal nanoparticles d) Insulating materials 	
		 7) Field-enhanced thermionic emission is related to: a) Tunnelling b) Schottky effect c) Poole-Frenkel effect d) Hopping conduction 	
		 8) Which technique uses a focused laser to transfer material onto a substrate? a) Sputtering b) Pulsed Laser Deposition c) Physical Vapor Deposition d) Chemical Vapor Deposition 	
	B)	 Fill in the blanks OR write true/false 1) Ball milling is a top-down approach to the fabrication of nanostructures. (True/False) 2) Excitons are formed when an electron and hole pair bind together. (True/False) 3) Rapid solidification is a bottom-up technique. (True/False) 4) Raman spectroscopy is used to study the electronic structure of carbon nanotubes. (True/False) 	04
Q.2		3() - /	12
	_ [Define quantum confinement in nanomaterials.	
	b) c)	What are exciton and its role in nanostructures? What is the significance of Raman spectroscopy in studying	
	C)	nanomaterials?	
	d)	Differentiate between photoluminescence and fluorescence.	
	•	What is the Schottky effect?	
	f)	• •	
	g) h)		
Q.3	Ans	swer the following (Any Three)	12
	a)		
	b)	Discuss the Poole-Frenkel effect and its significance in materials	
	٥)	Science. Describe the process and applications of Physical Vapor	
	c)	Describe the process and applications of Physical Vapor Deposition (PVD).	
	d)		

Q.4	Answer the following (Any Two)				
	a)	Discuss the top-down fabrication techniques in nanotechnology.			
	b)	Describe the synthesis and applications of carbon nanotubes.			
	c)	Explain the different types of luminescence observed in			
	·	nanomaterials and their significance.			
Q.5	Answer the following (Any two)				
	a)	Compare quantum dots with bulk semiconductors regarding electronic and optical properties.			
	b)	Explain the hopping conduction mechanism in low-dimensional systems.			
	c)	Discuss the electrical conduction mechanisms in insulators and			

compare them to those of metals.

Seat No.							Set	Р
	M.Sc. Physics (Material Science) (Semester - III) (Old) (CBCS) Examination: March/April - 2025 Semiconductor Physics (MSC03301)							
•			hursday, 15- M To 02:00 F	•		Мах	k. Marks	: 80
, , , , , , , , , , , , , , , , , , ,			2) Attempt a		s fror	m Q. No. 3 to Q. No. 7. arks.		
Q.1 .	A)		At 0 K the Fe		ution	function takes the simple rectangular the circular form	form	10
		2)	a) the intrinb) the intrinc) the intrin	sic level E_i is at the	ne value or the one mi			
		3)	a) Fermi lev	vel E_F	b)	tion $f(E)$ is symmetrical a conduction band edge I conduction band (C.B.)		
		4)	a) Smaller tb) equal toc) equal to	uctor absorbs phothan band gap en the band gap ene the band gap or lathe band gap or s	ergy ergy c arger	only		
		5)	When trapping a) $\tau_n \neq \tau_p$ c) $\tau_n = 0$	ng is present in th	b)	aterial: $ au_n = au_p \ au_p = 0$		
		6)	no barrier be that is prese a) an ohmic b) a rectifyir	etween the metal nt is so thin that of c contact	and t	constructed so that there he semiconductor, or any e carriers readily tunnel t ectifying	y barrier	

		7)	If $(a + b)$ is period of potential, then for such periodic potential; $V(x) = $				
			a) $V[x + (a + b)]$ b) $V[x/(a + b)]$				
			c) $V[x + (a - b)]$ d) $V[x * (a + b)]$				
		8)	is initial process that occurs in the formation of a crystal. a) Growth b) Nucleation c) atomic bonding d) Clusters				
		-	In case of crystal growth process the term LPE means a) Lower Potential Energy b) Local Potential Energy c) Liquid Phase Epitaxy d) Laser phase Epitaxy				
	1	•	In case of crystal growth process the abbreviation VPE meansa) Volume Phase Epitaxy b) Vapor Phase Epitaxy c) Variable Potential Energy d) Vapor Pressure Energy	.•			
	B)		in the blank OR Write True/False The high-field excitation of electrons into the indirect minima leads to the effect.) 6			
		2)	Semiconductor silicon (Si) has band gape energy; $E_g = $ eV.				
		•	Drift of charge carriers in a semiconductor is caused by The particle inside a box in a finite potential well can never be at				
		5)	rest, as it will violate Uncertainty Principle. The inverse effective-mass tensor is a symmetric tensor of the rank.				
		6)	The crystal growth technique MBE means				
Q.2	 Answer the following question a) Calculate the probability of an electron being thermally excited to an energy level which is 0.01 eV above the Fermi level. (Given: the 						
		Bol	tzmann constant, $k = 8.625 \times 10^{-5} \text{ eV/K}$, temperature, $T = 300 \text{ K}$				
	b)		d value of exponent base, $e = 2.71$). ccuss electrical conductivity and mobility in a semiconductor.				
	-	Cal	Iculate band gap energy of a semiconductor germanium (Ge) , in				
	d)		ctron volt, if it absorbs a photon of wavelength 1.77 micro meters. w trapping of charges carries occurs in semiconductors?				
Q.3	Ans	wer	the following question	16			
-,		Wri	ite a note on "group velocity of electrons." Obtain necessary				
	b)	•	pression. scribe in detail nucleation and growth theory of crystal growth process	; <u>.</u>			
Q.4	Ans	wer	the following question 1	16			
·	a)	Dis	cuss bonding forces in semiconductors.				
	b)	Dis	cuss in detail formation energies of liquid nuclei and crystalline nuclei				

Q.5	Ans a) b)	wer the following question Write a note on direct and indirect band gap materials. Explain how electric field is Built up by diffusion and drift of carries in the in semiconductor.	16
Q.6		wer the following question Discuss in detail "The Haynes-Shockley Experiment." Describe dynamics of electrons and holes inside a semiconductor.	16
Q.7		wer the following question Write a note on Fermi level pining. Explain Czochralski and liquid encapsulation techniques.	16

Seat	Sat	D
No.	Set	

M.Sc. Physics (Material Science) (Semester - III) (Old) (CBCS) Examination: March/April - 2025 Atomic and Molecular Physics (MSC03302)

Day & Date: Saturday, 17-May-2025 Max. Marks: 80

Time: 11:00 AM To 02:00 PM

Instructions: 1) Question No. 1 and 2 are compulsory.

- 2) Attempt any 3 questions from Q. No.3 to Q. No. 7.
- 3) Figures to the right indicate full marks.

Q.1 A) Choose correct alternatives:

10

- 1) Which interaction causes the splitting of spectral lines due to the interaction between the orbital motion of an electron and its spin?
 - a) Zeeman effect
 - b) Stark effect
 - c) Fine structure
 - d) Lamb shift
- 2) The fine structure of hydrogen atom includes which of the following corrections?
 - a) Relativistic correction
- b) Spin-orbit interaction

c) Lamb shift

- d) All of the above
- 3) What principle states that no two electrons in an atom can have the same set of four quantum numbers?
 - a) Hund's rule
 - b) Pauli exclusion principle
 - c) Aufbau principle
 - d) Heisenberg uncertainty principle
- What does the term "fine structure spectra" refer to in atomic physics?
 - Splitting of spectral lines due to the presence of an external electric field
 - Splitting of spectral lines due to the presence of an external magnetic field
 - Detailed splitting of spectral lines into closely spaced components
 - d) Spectral lines emitted in the X-ray region of the electromagnetic spectrum

- 5) What does the term "hyperfine structure spectra" refer to?
 - a) Splitting of spectral lines into closely spaced components due to nuclear spin
 - b) Splitting of spectral lines due to the presence of an external electric field
 - Detailed splitting of spectral lines into closely spaced components
 - d) Spectral lines emitted in the infrared region of the electromagnetic spectrum
- 6) Which theory describes how atomic orbitals combine to form molecular orbitals in a molecule?
 - a) Valence bond theory
- b) Molecular orbital theory
- c) Hybridization theory
- d) Electron affinity theory
- **7)** Which type of bonding involves the attraction between temporary dipoles in molecules?
 - a) Covalent bonding
- b) Ionic bonding
- c) Metallic bonding
- d) Van der Waals bonding
- 8) What principle states that the intensity of spectral lines in electronic transitions is proportional to the overlap of initial and final vibrational wavefunctions?
 - a) Morse oscillator principle
- b) Frank-Condon principle
- c) Born-Oppenheimer principle
- d) Rigid rotor principle
- 9) What are the group theoretical selection rules used for in infrared and Raman spectroscopy?
 - a) Determining the intensity of spectral lines
 - b) Predicting the positions of spectral lines
 - Identifying the presence of certain functional groups in molecules
 - d) Assigning the molecular weight of the molecule
- **10)** In electronic spectroscopy, what information can be obtained about molecular structure?
 - a) Molecular polarizability
 - b) Molecular vibrations
 - c) Molecular rotations
 - d) Energy levels and electronic transactions

Q.1 B) State whether true or false:

06

- a) Microwave spectroscopy is primarily used for the determination of electronic structures in molecules.
- b) Rotational Raman spectroscopy is a technique used to determine the rotational levels of molecules by measuring the intensity of Raman-scattered light as a function of frequency.
- c) Hybridization theory primarily depends on the electronegativity of atoms involved in bond formation.
- d) Van der Waals bonding involves the attraction between permanent dipoles in molecules.

		f)	become significant only for very high atomic numbers. The Pauli exclusion principle states that no two electrons in an atom can have the same set of quantum numbers.					
Q.2	Wr a)	Write short answers.a) Describe L-S coupling and j-j coupling for describing the coupling of						
	b) c)	Discus:	n spin and orbital angular momentum in atoms. s the concept of fine structure spectra in atomic physics. s the concept of hybridization in the context of molecular s and provide an example of a molecule with sp ³ hybridization.					
	d)		be the group theoretical selection rules for infrared and Raman ons in molecular vibrations.					
Q.3	Ana)	Explain how po electron Explain	e following: In the concept of atomic and molecular polarizability. Discuss plarizability influences the interaction of molecules with magnetic radiation in various spectroscopic techniques. In the principles of Raman spectroscopy for vibrational level ination.	16				
Q.4	Ana)	Explain includir rotation Explain	e following: In the rotational levels in diatomic and polyatomic molecules, In the Born-Oppenheimer approximation and selection rules for In al transitions. In the concept of hybridization in molecules with its types of In orbitals formed.	16				
Q.5	An	swer th	e following:	16				
	a) b)	discuss spectra Describ	the concept of the exchange effect in two-electron spectra & show the interaction between electrons leads to additional all features which influences the observed spectrum. See the principles of nuclear magnetic resonance (NMR) oscopy and electron spin resonance (ESR).					
Q.6	An		e following:	16				
	a)	Explair R bran	the vibration-rotation spectra and the significance of P, Q, and ches.					
	b)	•	the electronic spectra of diatomic molecules, emphasizing the Condon principle.					
Q.7		Explain	e following: Stem and Garlach Experiment and derive the expression for tion of an atom inside non-homogeneous magnetic field	16				

b) Explain Paschen-Back effect for 2S-2P transition.

e) Relativistic corrections for energy levels of the hydrogen atom

Seat	Sat	В
No.	Set	

M.Sc. Physics (Material Science) (Semester - III) (Old) (CBCS)

		Examination: Marc Materials Characteriza		
		e: Monday, 19-May-2025 D AM To 02:00 PM		Max. Marks: 80
Instruc	ction	ns: 1) Q.Nos.1 and 2 are compulso 2) Attempt any three questions 3) Figure to right indicate full m	from	
Q.1 A	,	Choose correct alternative. SI unit of thermal conductivity is Q a) WmK^{-1} c) Wm^2K	b)	as $_$ $Wm^{-1}k^{-1}$ Wm^2k^2
	2)	The representation of Beer Lamb represents absorption, 'b' represents concentration, what does 'a' represent a) Intensity c) Absorptivity	ents c	distance and 'c' represents
	3)	X-ray diffractometers provide compounds present in a solid sar a) Quantitative b) Qualitative c) quantitative and qualitative d) Either quantitative or qualitative	mple.	
	4)	There are main component a) Three c) Two	s in a b) d)	III spectrometers. Five Ten
	5)	By multiplying pumping speed by speed occurs, we get a measure a) vapour pressure c) Density	•	
	6)	The is a mathematical function of a wave diffracted from a diffraction factor c) intensity factor		

	7)	In Hall effect, is exerted on the charge carriers. a) Lorentz force b) Centripetal force c) Mechanical force d) All of these						
	8)	Radio waves have the wavelength in the electromagnetic spectrum.						
		a) Longest b) Shortest c) both (a) and (b) d) none of these						
	9)	In four probe method, voltage is read across inner probes. a) Four b) Three c) Two d) both (b) and (c)						
	10) B)	 DTA stands for a) Distribution Thermal Analysis b) Destructive Thermal Analysis c) Dimensional Thermal Analysis d) Differential Thermal Analysis Fill in the blanks or State True/False: a) Thermogravimetric analysis is used for measuring thermal stability. (True/False) b) The oil in Rotary pump doesn't provide seal between rotor and pump ring. (True/False) c) Gamma rays have the shortest wavelength in the electromagnetic spectrum. (True/False) 	06					
		 d) In a cubic lattice, all the angles are equal to degrees. e) In semiconductors having positive Hall coefficient, are majority carriers. f) Refractive index has unit. 						
Q.2	a) \ b) \ c)	Wer the following: What are the different factors affecting the intensity in Powder X-ray Diffraction? State the various Resonance techniques and mention their necessities in short. Draw the neat labelled diagram showing construction of UV-Vis absorption spectroscopy. State the postulates of kinetic theory of gases.	16					
Q.3	a) i	wer the following: Describe in detail about absorption, refection and transmission in materials.	16					
	b) I	Explain in detail about the working principle of Roots pump.						

Q.4	Ans a) b)	wer the following What is a spectrometer? Explain its working and applications Elaborate the basic principle of electrical transport in metals and semiconductors.	16
Q.5	Ans a) b)	wer the following Explain the working of a Rotary Oil pump. Describe the technique of measurement of band gap in solids using Photoluminescence spectroscopy.	16
Q.6	Ans a) b)	wer the following Explain the Four probe method for conductivity measurement. Using the kinetic theory of gases, obtain an expression for the relation between total kinetic energy, pressure, and volume of the gas.	16
Q.7	Ans a) b)	wer the following Explain the methods of sample preparation. Describe in detail about the Hall effect in semiconductors.	16

Seat No.					Set	Р
M	.Sc. F	Exam	I Science) (Se ination: Marcl nductor Devic	h/Ap		
•		Wednesday, 14-N PM To 06:00 PM	/lay-2025		Max. Marks	: 80
Instru	ctions	s: 1) Q. Nos (1) an 2) Attempt any t 3) Figures to the	hree questions t	from	Q. No (3) to Q. No. (7)	
Q.1 <i>A</i>	A) C 1)	noose the correct In a heterojunction a) n-type c) both (a) and	on LASER,	b)	aterials are present. p-type only n-type	10
	2)	When a voo a) breakdown c) high	oltage is applied	to to b)	he gate, the NMOS will conduct low both (a) and (b)	t.
	3)		y charge carriers	s. b)		
	4)	Flat-Band refers voltage drop. a) little c) not defined	to the biasing co	ondit b) d)	no all of these	
	5)	When the curren contact, the cont a) Rectifying c) Resistive				
	6)	The point in the obegins to flow is a) cut-off voltage c) threshold vo	called as ge	-	•	
	7)	The readout circle a) parallel to se		orm b)	a conversion. series to parallel	

d) all of these

c) parallel to parallel

		8)		ks into a pix	defined as kel during th		re time pres	•	of light.	
		9) 10)	To a) c)	increase fri reduced unchange negative o theory. RWH	inging field,	CCD gate b) d) esistance b)	e lengtl enh all c is the Hall	n needs to anced f these	be	
	B)	Fill 1) 2) 3) 4) 5) 6)	NM Fe the A h the Wh con Ph	MOS works rmi-level pi e metal-sem elect e energy banen the SC nduction state otodiodes of e number of	niconductor tron energy and diagram R is turned f ate is called operate afte	PMOS. (1 tered pote junction. is represe from forward as btrons process.)	True Fantially (True/Fented bulse) ard blo	by the insufalse) by the higher cking to fo	ulator layer at er position in rward the number of	06
Q.2	An a) b) c) d)	Wr Dra Wr	Ver the following question Vrite in brief about concept of the dark current. Draw a neat labelled diagram showing construction of Gunn diode. Vrite the difference between in depletion and enhancement MOSFET. Draw a labelled diagram showing construction of Solar Cell.						16	
Q.3	An a) b)	Ela for	for quantum efficiency of solar cell.					08 08		
Q.4	An a) b)	and working of LEDs.						08		
Q.5	An a) b)	mechanism in Schottky diode.							08 08	

Q.6	Ansa)	mechanism in two phase CCD.				
Q.7	,	swer the following question	80			
.	a)	Give detailed explanation about the construction and working of p-n	08			
	b)	junction LASER. What are Photoconductors? Write in brief about photocurrent gain.	08			

Seat No.					Set P
N	1.Sc	c. P	hysics (Material Science) (S Examination: Mar Nuclear and Particle P	ch/A	-
•			Friday, 16-May-2025 PM To 06:00 PM		Max. Marks: 80
Instru	uctio	ons	1) Q. Nos. 1 and 2 are compul2) Attempt any three questions3) Figures to the right indicate	s fror	n Q. No. 3 to Q. No. 7.
Q.1	A)	_	noose the correct alternative.	n io	10
		1)	The binding energy per nucleof following elements? a) Helium c) Uranium	b) d)	Iron Hydrogen
		2)	The theory explaining alpha de a) Quantum tunnelling b) Gravitational force c) Electromagnetic interaction d) Thermal diffusion		is based on which phenomenon?
		3)	The quark composition of a proa) uuu c) udd	oton b) d)	is: uud ddu
		4)	Which nuclear model consider incompressible nuclear fluid? a) Shell model c) Liquid drop model	b)	Fermi gas model
		5)	The primary component of cos a) Electrons c) Protons	smic b) d)	rays is: Neutrons Gamma rays
		6)	Yukawa's theory describes nu of particle? a) Electron	clear b)	forces as mediated by which type Neutrino

d)

7) The half-life of a radioactive substance is the time taken for its activity

b)

d)

Photon

Double

Become constant

c) Meson

to: _____.

a) Reduce to zero

c) Reduce to half

		8)	Magic numbers are associated with which nuclear property? a) Nuclear spin b) Nuclear stability c) Decay constant d) Isotopic mass	
		9)	The conservation law not obeyed in weak interactions is: a) Charge conservation b) Parity conservation c) Energy conservation d) Baryon number conservation	
	1	10)	A synchrotron is used to: a) Accelerate particles in a straight line b) Detect cosmic rays c) Accelerate particles in a circular path d) Measure binding energy	
	B)	1)	in the blanks OR write true/false. The energy released during nuclear fusion is due to the conversion of into energy. The shell model explains the concept of numbers for	;
			stable nuclei. In beta decay, a neutron converts into a and emits a beta	
		,	particle and an antineutrino. Cosmic rays are primarily composed of heavy nuclei. True/False	
		-	The binding energy per nucleon decreases for elements heavier than iron. True/False	
		6)	Alpha particles have higher penetration power than beta particles. True/False:	
Q.2	Ans a)	Exp	the following. lain the concept of nuclear binding energy and its relation to lear stability.	>
	b)	Des	scribe the liquid drop model and its applications in predicting lear masses.	
	c)	Wh	at is Yukawa's hypothesis of nuclear forces? Explain the role of sons.	
	d)		cuss the process of radioactive dating and its applications.	
Q.3	Ans a) b)	Exp De:	the following. Idain the Fermi gas model and how it applies to the nucleus. Is scribe the shell model of the nucleus with an emphasis on the nucleus interaction.	;
Q.4	Ans a) b)	De Dis	the following. ive the Breit-Wigner formula for nuclear resonance reactions. cuss the theory of alpha decay and the concept of quantum nelling.	;

16

		atmosphere.	
Q.6	Ans a) b)	wer the following. Explain nuclear fission and fusion with suitable examples. Describe the functioning of a cyclotron and its application in nuclear physics.	16
Q.7	Ans	wer the following	16
	a)	Discuss the conservation laws in nuclear reactions with examples.	
	b)	Explain the working principle of scintillation detectors and their applications.	

Classify elementary particles based on their interactions. Explain with

What are cosmic rays? Discuss their origin and effects on the Earth's

Q.5 Answer the following.

b)

Seat No.			Set P
M	Ex	erial Science) (Seme amination: March/A cs of Nano Material	-
•	Date: Tuesday, 20-M 03:00 PM To 06:00 P	•	Max. Marks: 80
Instru		ve questions. Q (2) are compulsory. ny three from Q.3 to Q	.7.
Q.1 <i>i</i>	A) Select the correct 1) In bottom-u a) atoms c) molecule	p approach the buildin b)	g blocks can be clusters all above
	 2) The surface is a) 10⁸ c) 10⁷ 	e area to volume ratio d b) d)	of a sphere with radius 30 nm 10^6 10^9
	-	peak exhibits	les decreases then the position no shift none of the above
	4) Similar to the gapa) ~ 4.5 eV c) ~ 5.5 eV	·	nitride nanotubes have a band ~ 5 eV none of the above
	5) The contrastimaging.	st transfer function frec	quently referred to in

b)

d)

b)

d)

7) The conductivity expression in Arrehenious type thermally activated

6) The temperature below red heat, thermionic emission from

conduction can be given by the relation _____.

HRTEM

FESEM

negative all of above

a) TEM

c) SEM

a) positive

c) constant

uncharged bodies is chiefly _

a) $\sigma = \sigma_0 \exp(E_a/kT)$

c) $\sigma = \sigma_0 \exp(-E_a/kT)$

b) $\sigma = -\sigma_0 \exp(E_a/kT)$ d) all of above

		8) If an electron is confined in limited space, then the allowed energy	
		states are a) continuous b) limited	
		c) discrete d) none of the above	
		9) DC sputtering cannot be used for deposition of a) Metal b) Oxide	
		c) Alloys d) All above	
		 10) For emission of the electrons from the metal surface the minimum required energy is a) work function of the metal b) kinetic energy of the electron c) binding energy of the electron d) None of the above 	
	B)	State whether true or false/ Fill in the blanks.	06
		 The estimated tensile strength of CNT is At present the highest resolution of HRTEM realised is 	
		3) In SEM the morphology of the sample is achieved with the help of	
		4) STM is based on the concept of quantum tunnelling.	
		5) The SPR is observed for insulator nanoparticles.6) AFM use feedback to regulate the current on the sample.	
		of the decree and regulate the carrent of the cample.	
Q.2		e short notes on.	16
	-	Nanobiometric Molecular machines	
	,	Assumptions of Free Electron model.	
	d)	Surface Plasmon resonance (SPR)	
Q.3	a) b)	Describe principle and operation of TEM. Why is spatial resolution of STM better than AFM?	10 06
Q.4	a)	Describe various process involved in the synthesis of metal oxides by	10
Q. 7	aj	sol-gel method.	10
	b)	Advantages of chemical method of synthesis of nanomaterials.	06
Q.5	a)	Give an account of Top-down vs. Bottom-up techniques of nanofabrication.	10
	b)	Explain the basic difference between a PVD and CVD process.	06
Q.6	a)	Derive the AC electrical conductivity of a metal according to Drude	10
	b)	model. Explain the inadequacies of Drude model. Explain how endo-fullerenes can be used as one-dimensional metal-semiconductor junctions.	06

Q.7	a)	What is a carbon nanotube? Explain types of carbon nanotubes.	10
	b)	Give an account of Template-assisted synthesis of nano-wires/rods.	06

Seat	Sat	D
No.	Set	

M.Sc. Physics (Material Science) (Semester - IV) (New/Old) (CBCS) Examination: March/April - 2025 Advanced Techniques of Materials Characterization (MSC03406)

	Advan	ced Techniques of M	aterials	Characterization (N	ISC03406)
-		Thursday, 22-May-2025 PM To 06:00 PM			Max. Marks: 80
Inst	ructions	: 1) Q. Nos 1 and 2 are of 2) attempt any three from 3) Figure to the right in	om Q. N	o. 3 to Q. No. 7.	
Q.1	1) F	ultiple choice question Raman spectroscopy is b Elastic scattering	ased on b)	Inelastic scattering	10
	c)	Both a) and b)	d)	None of the above	
	-	Vhich type of spectrosco	py relies	on the scattering of lig	ht by
		Raman spectroscopy			
	C)	UV-Vis spectroscopy	a)	NIVIR spectroscopy	
	a) b) c)	n SEM, once an electron Electrons and x-rays Positrons and gamma Anti-electrons and ultra Neutrinos and radio wa	rays aviolet ra		ie ejects
	4) V	Vhat is the typical size ra	ange of r	nanoparticles?	
		1 to 100 millimeters	-		
	c)	1 to 100 nanometers	d)	1 to 100 picometers	
	_	than visible light TEM can achieve grea	 n size th waves h ter mag	an light microscope ave wavelengths much	shorter
	6) F	Raman effect is a scatter	ing of	·	
		Atoms	b)	Molecules	
	c)	Protons	d)	Photons	
		Vhich of the following lin			
	a)	Stokes lines	p)	Rayleigh-scattered lin	
	c)	Anti-strokes lines	d)	All have the same into	FIIOILY

	8)		technique is used for th SEM BET	e det b) d)	ermination of surface area. TEM None of these	
	-	a) c)	naterials? Carbon Magnesium	b) d)	e most commonly used anode Tungsten Cesium	
	10)	R a) b)	eflection (ATR) accessory? To increase the intensity o To reduce sample heating To improve the resolution	f the durir	ng analysis	
	2	1) ; 2) ; 3) ; 4) ; 5) ;	directly proportional to the of the lectron spectroscopy neethe sample. X-ray Photoelectron Spectro the elemental composition of the scanning electron micros secondary electrons. The resolution of an optical increasing the magnification	once utron oscop of a s copy micro alor icroso	beam is used for the analysis of by (XPS) can be used to determine ample's surface. an image is formed by using bscope can be improved by le. copy (TEM), the sample must be	06
Q.2	a)	Ex Dis els els Ex	scuss the significance of the scuss the limitations of light ectron microscopy. plain the principle of diffract addition.	Airy micro	f light in optical microscopy. disc in determining resolution. escopy and the advantages of f light and the Braggs diffraction spectroscopy in various fields.	16
Q.3	Ansa)	Dis line De	e widths, and methods for e	leme ation	S, including core level splitting, ntal analysis. in optical microscopy. Describe	16

Q.4	 Answer the following: a) Write in detail schematic of complete SEM. b) Explain the concept of wavelength of electrons and its significance in electron microscopy. Discuss the theoretical resolving power of electron microscopes 	16
Q.5	 Answer the following: a) Write about different types of optical microscopes. b) Explain the process of energy analysis in XPS, including energy 	16

Q.6 Answer the following:

and charging effects.

16

a) Discuss the basic setup and operational principles of Transmission Electron Microscopy (TEM), including electron diffraction and image formation.

analyzers and X-ray sources. Discuss sample selection, preparation,

b) Explain the classical and quantum theories of the Raman effect. Discuss the rotational and vibrational structure of Raman spectra with examples.

Q.7 Answer the following:

16

- a) Compare and contrast Raman spectroscopy and FTIR spectroscopy in terms of their principles, strengths, and limitations.
- **b)** Outline the components of the optical column in an electron microscope and explain the function of magnetic lenses.